

MCH3382

Power MOSFET -12V, 198mΩ, -2A, Single P-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

Features

- Low On-Resistance
- 1.2V drive
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

- Load Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1, 2)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	-12	V
Gate to Source Voltage	V _{GSS}	±9	V
Drain Current (DC)	I _D	-2	A
Drain Current (Pulse) PW ≤ 10μs, duty cycle ≤ 1%	I _{DP}	-8	A
Power Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm)	P _D	0.8	W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2 : This product is designed to "ESD immunity < 200V*", so please take care when handling.

*Machine Model

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² × 0.8mm)	R _{θJA}	156.2	°C/W

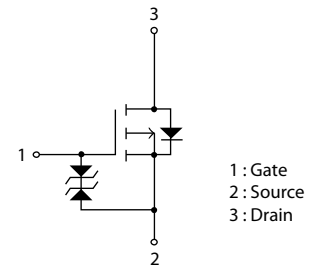


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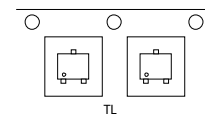
www.onsemi.com

V _{DSS}	R _{DS(on)} Max	I _D Max
-12V	198mΩ@ -4.5V	-2A
	297mΩ@ -2.5V	
	429mΩ@ -1.8V	
	1040mΩ@ -1.2V	

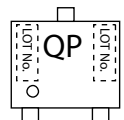
ELECTRICAL CONNECTION P-Channel



PACKING TYPE : TL



MARKING



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

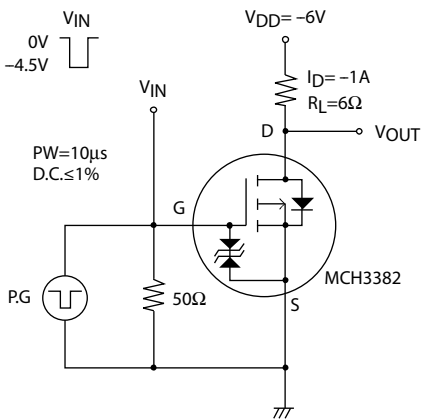
MCH3382

ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 3)

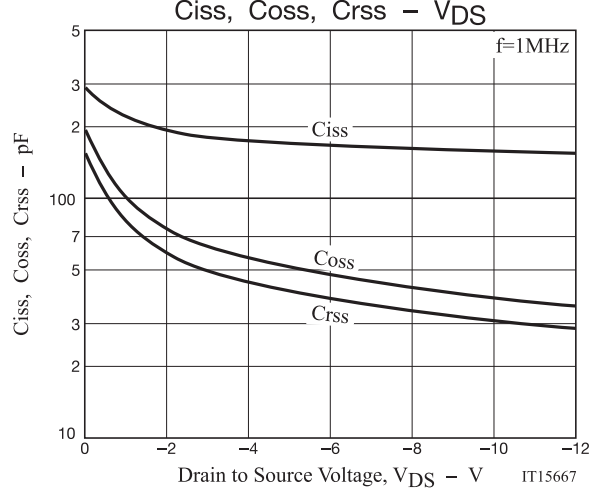
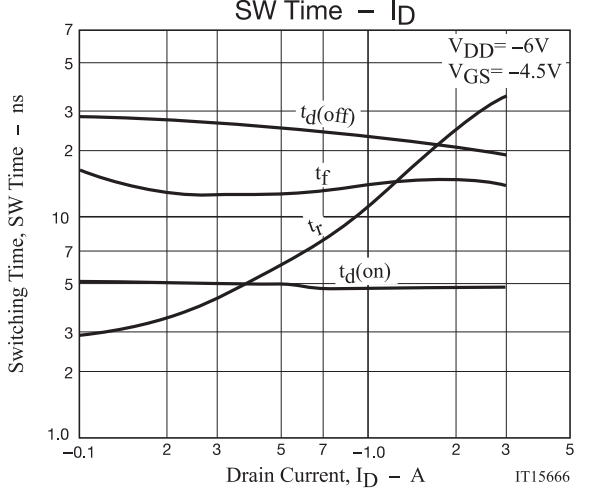
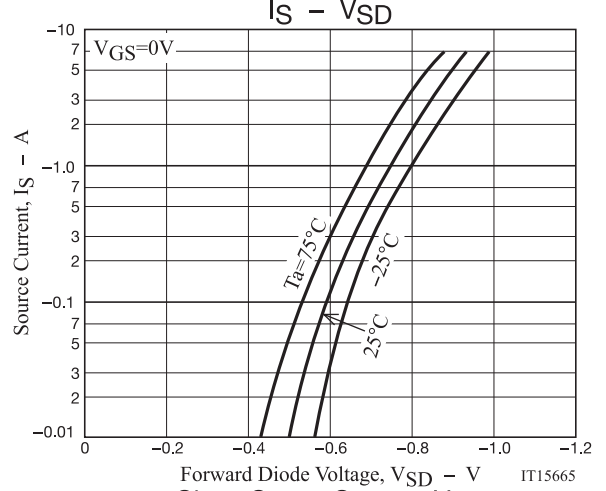
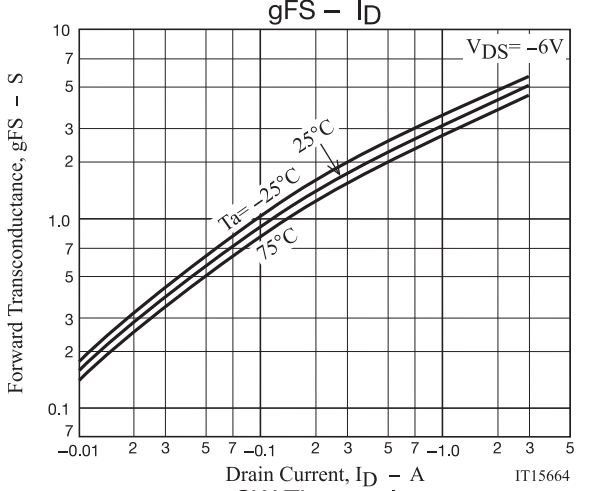
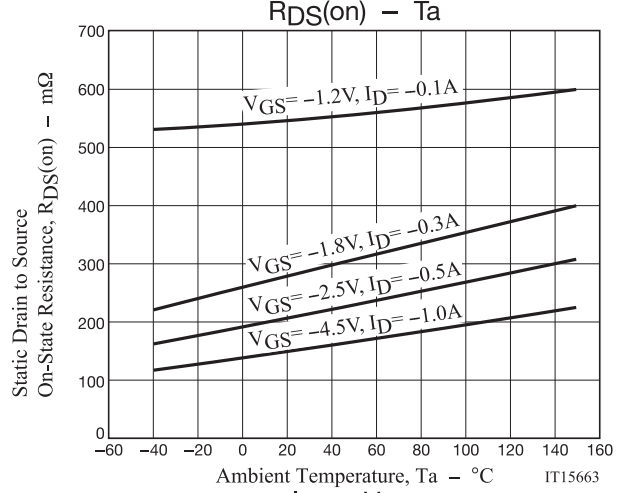
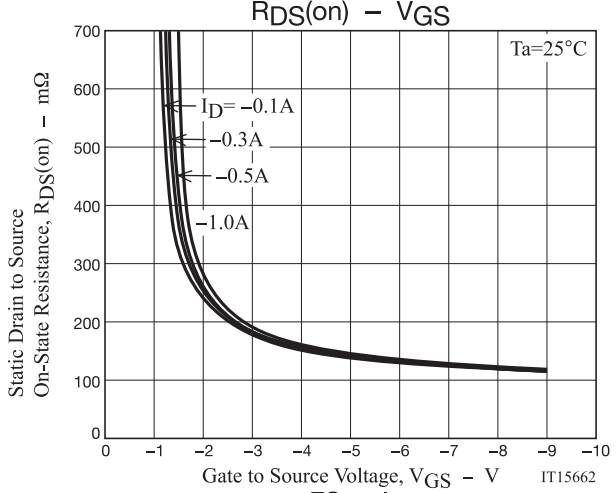
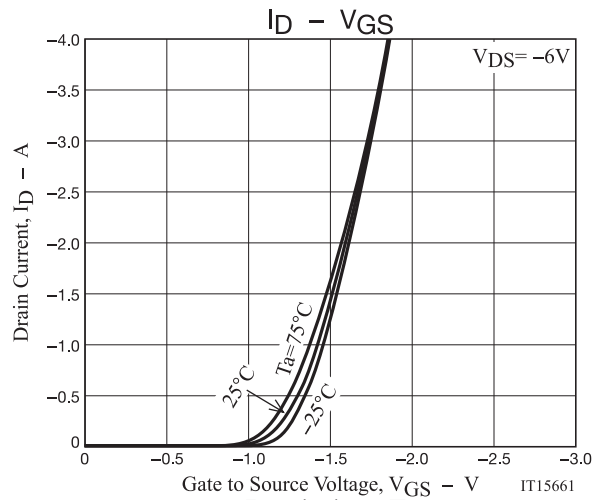
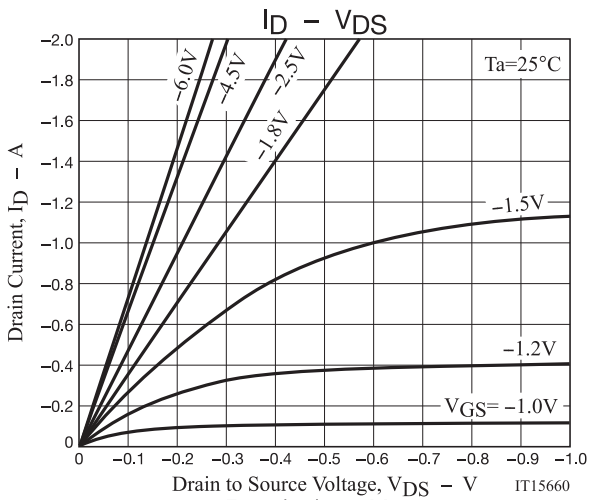
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-12			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-12V, VGS=0V			-10	μA
Gate to Source Leakage Current	IGSS	VGS=±7.2V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=-6V, ID=-1mA	-0.3		-0.9	V
Forward Transconductance	gFS	VDS=-6V, ID=-1A		3		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=-1A, VGS=-4.5V		152	198	mΩ
	RDS(on)2	ID=-0.5A, VGS=-2.5V		212	297	mΩ
	RDS(on)3	ID=-0.3A, VGS=-1.8V		286	429	mΩ
	RDS(on)4	ID=-0.1A, VGS=-1.2V		520	1040	mΩ
Input Capacitance	Ciss	VDS=-6V, f=1MHz		170		pF
Output Capacitance	Coss			50		pF
Reverse Transfer Capacitance	Crss			40		pF
Turn-ON Delay Time	tj(on)			4.8		ns
Rise Time	tr	See specified Test Circuit		11		ns
Turn-OFF Delay Time	tj(off)			23		ns
Fall Time	tf			14		ns
Total Gate Charge	Qg	VDS=-6V, VGS=-4.5V, ID=-2A		2.3		nC
Gate to Source Charge	Qgs			0.40		nC
Gate to Drain "Miller" Charge	Qgd			0.46		nC
Forward Diode Voltage	VSD		IS=-2A, VGS=0V		-0.85	-1.2

Note 3 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

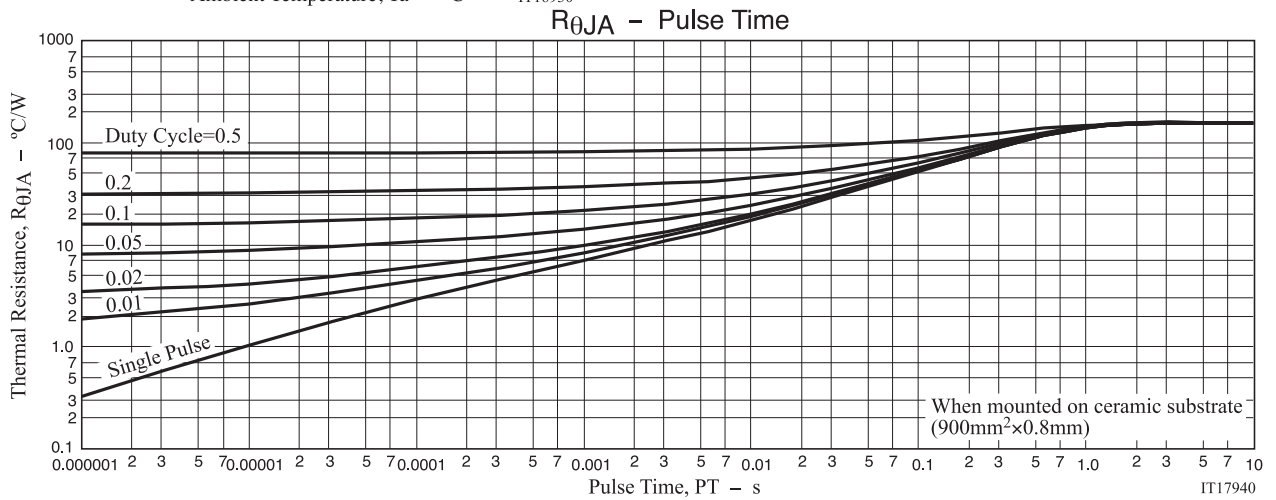
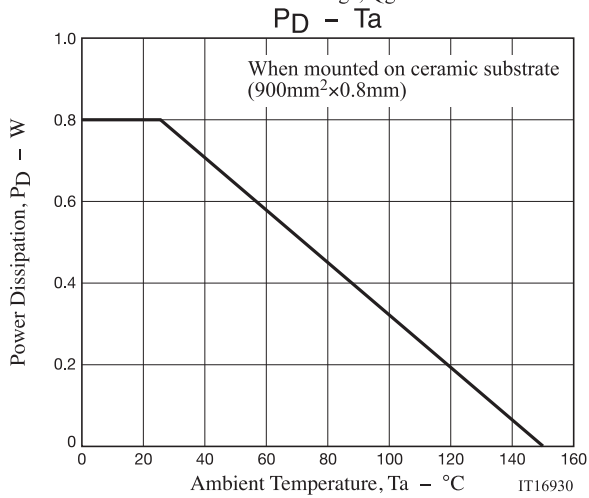
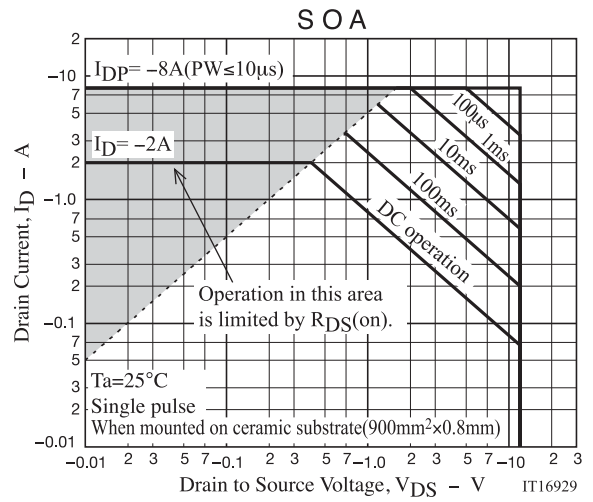
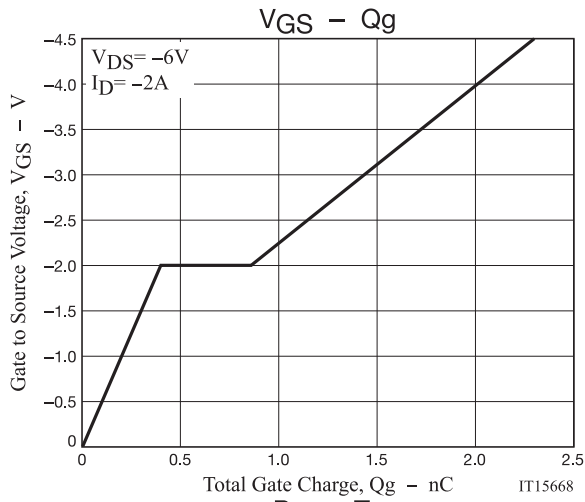
Switching Time Test Circuit



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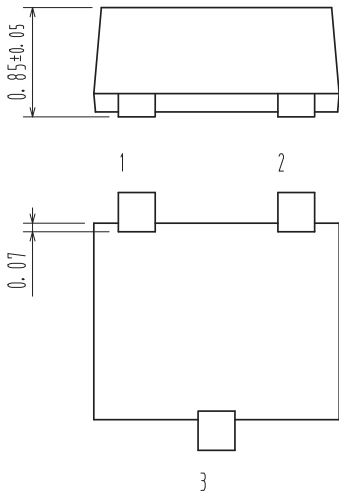
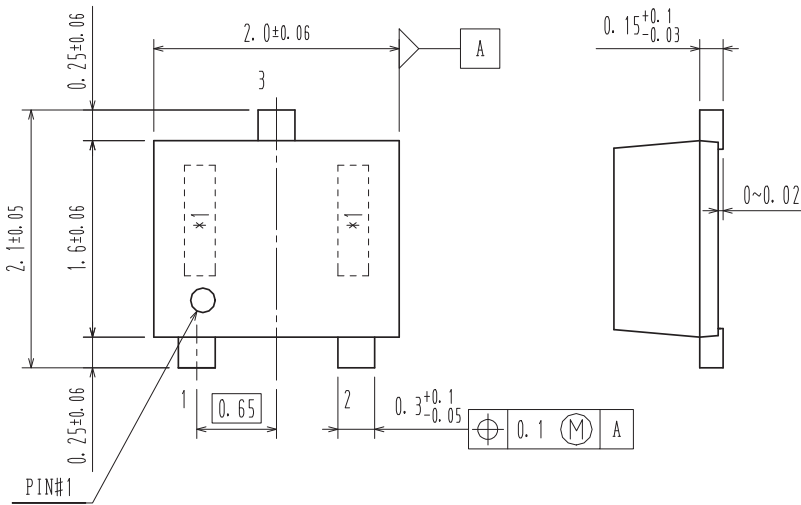


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PACKAGE DIMENSIONS

unit : mm

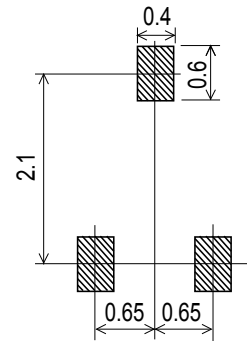
SC-70FL / MCPH3
CASE 419AQ
ISSUE O



*1: Lot indication

- 1 : Gate
- 2 : Source
- 3 : Drain

Recommended Soldering Footprint



ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
MCH3382-TL-H	QP	SC-70FL / MCPH3 (Pb-Free / Halogen Free)	3,000 / Tape & Reel
MCH3382-TL-W			

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the MCH3382 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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